SFH 4250

Power TOPLED®

High Power Infrared Emitter (850 nm)











Applications

- CCTV Surveillance
- Gaming, Amusement, Gambling
- Gesture Recognition

- Industrial Automation (Machine Controls, Light Barriers, Vision Controls)
- Safety and Security, CCTV
- White Goods

Features:

- Package: clear epoxy
- Qualifications: The product qualification test plan is based on the guidelines of AEC-Q101-REV-C,
 Stress Test Qualification for Automotive Grade Discrete Semiconductors.
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- High forward current allowed at high temperature
- High Power Infrared LED
- Short switching times

Ordering Information

Туре	Radiant intensity 1)	Radiant intensity 1) typ.	Ordering Code
	$I_{\rm F} = 100 \text{ mA}; t_{\rm p} = 20 \text{ ms}$ $I_{\rm e}$	$I_{\rm F} = 100 \text{ mA}; t_{\rm p} = 20 \text{ ms}$ $I_{\rm e}$	
SFH 4250-Z	10.0 32.0 mW/sr	20 mW/sr	Q65110A2465
SFH 4250-R2S-Z	12.5 32.0 mW/sr	20 mW/sr	Q65110A7238
SFH 4250-S	16.0 32.0 mW/sr	20 mW/sr	Q65111A2957



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Maxi	mum	Ratin	as

$T_{\Lambda} = 25 ^{\circ}$)
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Parameter	Symbol		Values
Operating temperature	T _{op}	min. max.	-40 °C 100 °C
Storage temperature	T_{stg}	min. max.	-40 °C 100 °C
Reverse voltage ²⁾	V_R	max.	12 V
Forward current	I _F	max.	100 mA
Surge current $t_p \le 100 \mu s; D = 0$	I _{FSM}	max.	1 A
Power consumption	P _{tot}	max.	180 mW
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}	max.	2 kV



Characteristics

 $I_{_{\rm F}}$ = 100 mA; $t_{_{
m p}}$ = 20 ms; $T_{_{
m A}}$ = 25 °C

Parameter	Symbol	Values	
Peak wavelength	λ_{peak}	typ.	860 nm
Centroid wavelength	$\lambda_{ ext{centroid}}$	typ.	850 nm
Spectral bandwidth at 50% I _{rel,max}	Δλ	typ.	30 nm
Half angle	φ	typ.	60 °
Dimensions of active chip area	LxW	typ.	0.3 x 0.3 mm x mm
Rise time (10% / 90%) $I_F = 100 \text{ mA}; R_L = 50 \Omega$	t _r	typ.	12 ns
Fall time (10% / 90%) $I_F = 100 \text{ mA}; R_L = 50 \Omega$	t _f	typ.	12 ns
Forward voltage	V_{F}	typ. max.	1.5 V 1.8 V
Forward voltage $I_F = 1 \text{ A}; t_p = 100 \mu\text{s}$	V_{F}	typ. max.	2.4 V 3 V
Reverse current $^{2)}$ $V_R = 5 V$	I _R	max. typ.	10 μA 0.01 μA
Total radiant flux 3)	Фе	typ.	60 mW
Radiant intensity ¹⁾ $I_F = 1 \text{ A}; t_p = 25 \mu \text{s}$	l _e	typ.	160 mW/sr
Temperature coefficient of brightness	TC _i	typ.	-0.5 % / K
Temperature coefficient of voltage	TC _v	typ.	-0.7 mV / K
Temperature coefficient of wavelength	$TC_{_{\lambda}}$	typ.	0.3 nm / K
Thermal resistance junction ambient real 4)	R_{thJA}	max.	300 K / W
Thermal resistance junction solder point real 5)	R_{thJS}	max.	140 K / W



Brightness Groups

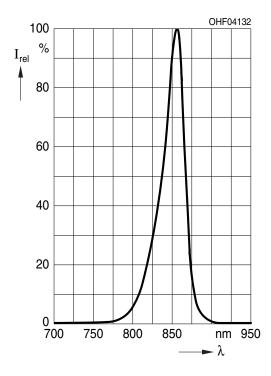
 $T_A = 25$ °C

Group	Radiant intensity $I_F = 100 \text{ mA}$; $t_p = 20 \text{ ms}$ min.	Radiant intensity $I_F = 100 \text{ mA}$; $t_p = 20 \text{ ms}$ max.
	l _e	I _e
R1	10.0 mW/sr	16.0 mW/sr
R2	12.5 mW/sr	20.0 mW/sr
S	16.0 mW/sr	32.0 mW/sr

Only one group in one packing unit (variation lower 2:1).

Relative Spectral Emission 6), 7)

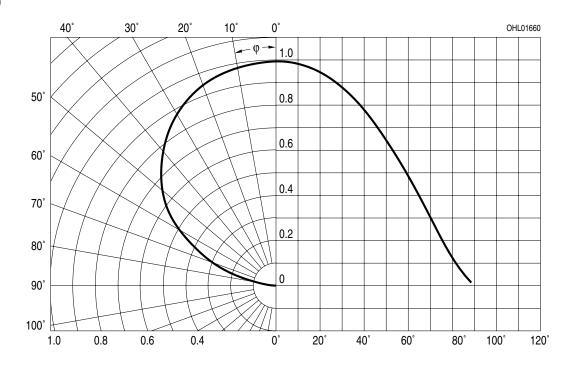
$$I_{rel} = f(\lambda); I_{F} = 100 \text{ mA}; t_{p} = 20 \text{ ms}$$





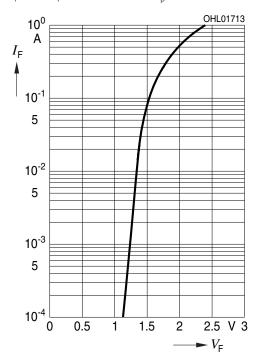
Radiation Characteristics 6), 7)

$$I_{rel} = f(\phi)$$



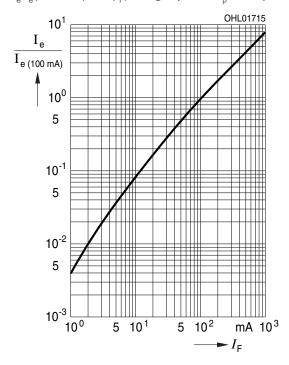
Forward current 6), 7)

 $I_F = f(V_F)$; single pulse; $t_p = 100 \mu s$



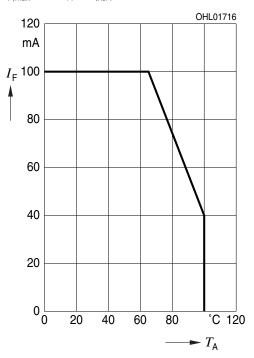
Relative Radiant Intensity 6), 7)

 $I_e/I_e(100\text{mA}) = f(I_F)$; single pulse; $t_p = 25 \mu s$



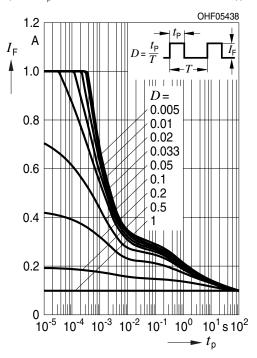
Max. Permissible Forward Current

$$I_{F,max} = f(T_A); R_{thJA} = 300 \text{ K} / \text{W}$$



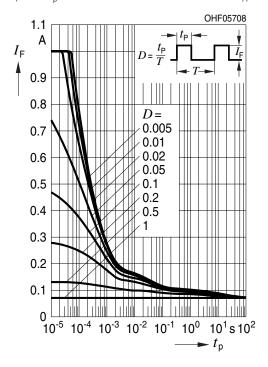
Permissible Pulse Handling Capability

 $I_F = f(t_p)$; duty cycle D = parameter; $T_A = 25$ °C

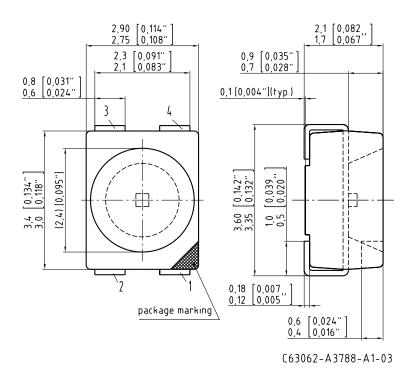


Permissible Pulse Handling Capability

 $I_F = f(t_p)$; duty cycle D = parameter; $T_A = 85$ °C



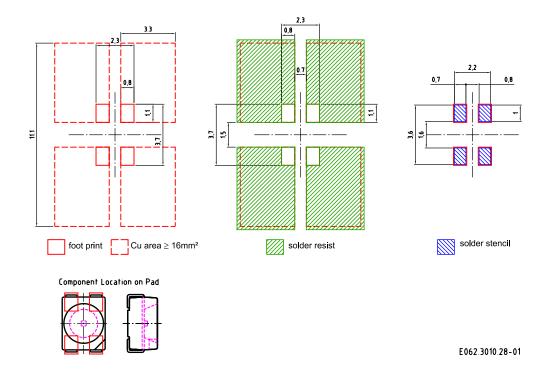
Dimensional Drawing 8)



Approximate Weight: 31.0 mg **Package marking:** Cathode

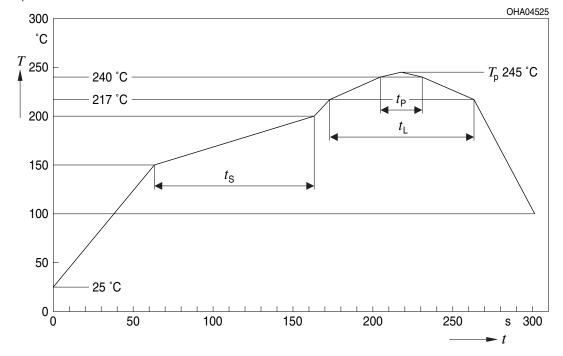
Pin	Description
1	Cathode
2	Anode
3	Anode
4	Anode

Recommended Solder Pad 8)



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



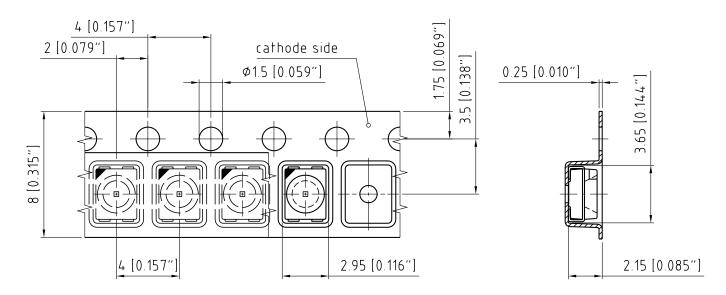


SFH 4250

Profile Feature	Symbol	Pb Minimum	-Free (SnAgCu) Ass Recommendation	sembly Maximum	Unit
Ramp-up rate to preheat*) 25 °C to 150 °C		- IVIII III TGITT	2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t _s	60	100	120	S
Ramp-up rate to peak*) T _{Smax} to T _P			2	3	K/s
Liquidus temperature	T _L		217		°C
Time above liquidus temperature	t _L		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	S
Ramp-down rate* T _p to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

Taping 8)

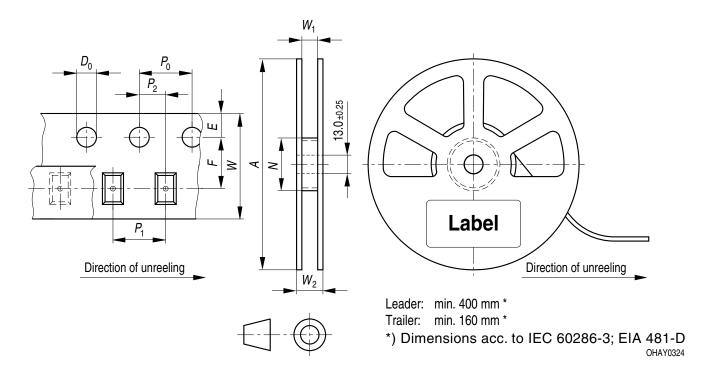


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^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Tape and Reel 9)

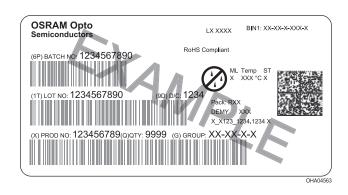


Reel dimensions [mm]

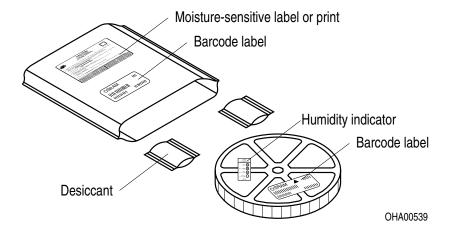
Α	W	N_{\min}	W_1	$W_{2\text{max}}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1	60	8.4 + 2	14.4	2000
330 mm	8 + 0.3 / - 0.1	60	8.4 + 2	14.4	8000



Barcode-Product-Label (BPL)



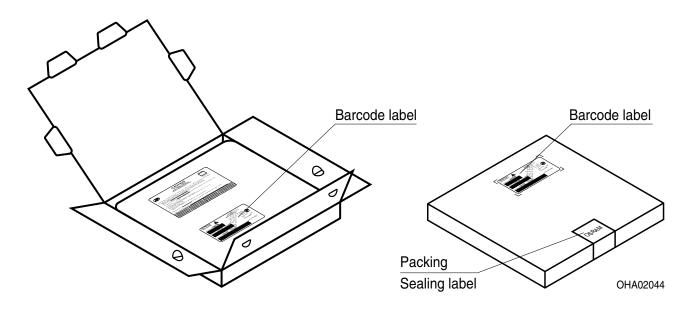
Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Transportation Packing and Materials 8)



Dimensions of transportation box in mm

Width	Length	Height
200 ± 5 mm	195 ± 5 mm	30 ± 5 mm
352 ± 5 mm	352 ± 5 mm	33 ± 5 mm



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit www.osram-os.com/appnotes



Disclaimer

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the OSRAM OS Webside.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.



Glossary

- Radiant intensity: Measured at a solid angle of $\Omega = 0.01 \text{ sr}$
- ²⁾ **Reverse Operation**: Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- Total radiant flux: Measured with integrating sphere.
- Thermal resistance: junction ambient, mounted on PC-board (FR4), padsize 16 mm² each
- Thermal resistance: junction soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Testing temperature: $T_A = 25^{\circ}C$
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ⁹⁾ **Tape and Reel**: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



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